

December 2014

FCH041N60E N-Channel SuperFET[®] II Easy-Drive MOSFET 600 V, 77 A, 41 mΩ

Features

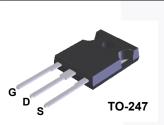
- 650 V @ T_{.I} = 150°C
- Typ. R_{DS(on)} = 36 mΩ
- Ultra Low Gate Charge (Typ. Q_q = 285 nC)
- Low Effective Output Capacitance (Typ. Coss(eff.) = 735 pF)
- 100% Avalanche Tested
- An Integrated Gate Resistor
- RoHS Compliant

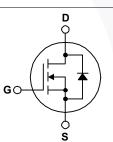
Applications

- LCD / LED / PDP TV Lighting
- Solar Inverter
- AC-DC Power Supply

Description

SuperFET[®] II MOSFET is Fairchild Semiconductor's brand-new high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low on-resistance and lower gate charge performance. This technology is tailored to minimize conduction loss, provide superior switching performance, dv/dt rate and higher avalanche energy. Consequently, SuperFET II MOSFET easy-drive series offers slightly slower rise and fall times compared to the SuperFET II MOSFET series. Noted by the "E" part number suffix, this family helps manage EMI issues and allows for easier design implementation. For faster switching in applications where switching losses must be at an absolute minimum, please consider the Super-FET II MOSFET series.





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol		Parameter	FCH041N60E	Unit		
V _{DSS}	Drain to Source Voltage		600	V		
V _{GSS}	Cata ta Cauraa Valtaga	- DC	- DC		V	
	Gate to Source Voltage	- AC (f > 1 Hz)		±30	- V	
ID	Drain Current	- Continuous (T _C = 25 ^o C)		77	^	
	Drain Current	- Continuous (T _C = 100 ^o C)		48.7	Α	
I _{DM}	Drain Current	- Pulsed	231	А		
E _{AS}	Single Pulsed Avalanche Energy (Note 2)			2025	mJ	
I _{AR}	Avalanche Current (Note 1)			15	А	
E _{AR}	Repetitive Avalanche Energy (Note 1)			5.92	mJ	
du/dt	MOSFET dv/dt		100	V/ns		
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	20	V/IIS		
P _D	Dower Dissinction	(T _C = 25 ^o C)		592	W	
	Power Dissipation	- Derate Above 25°C		4.74	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to +150	°C	
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds			300	°C	

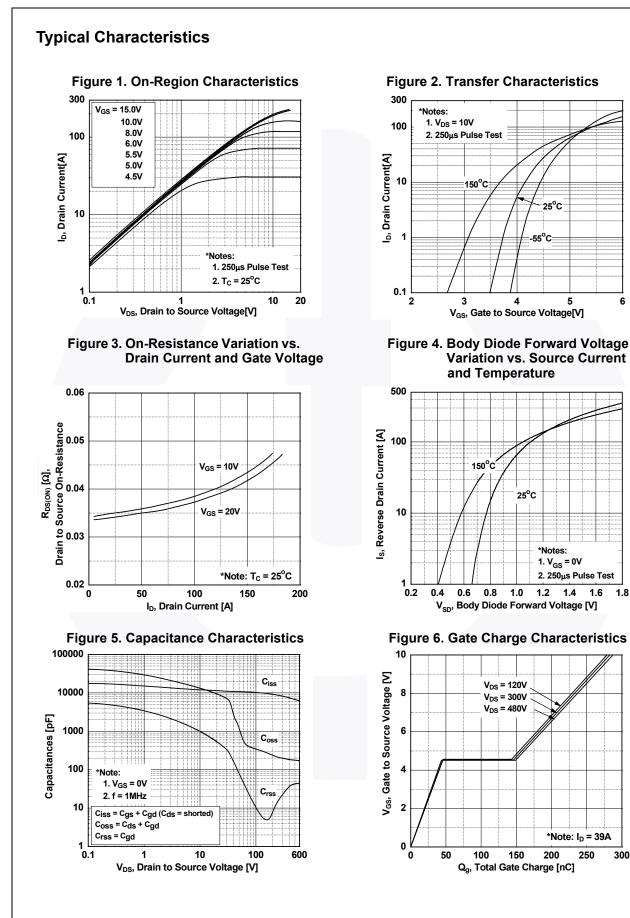
Thermal Characteristics

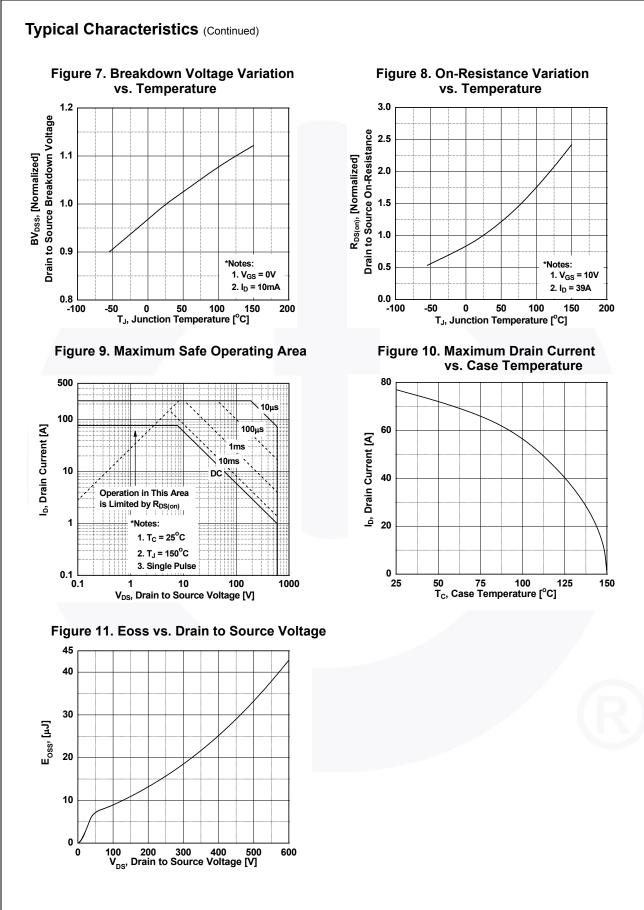
Symbol	Parameter	FCH041N60E	Unit	
R_{\thetaJC}	Thermal Resistance, Junction to Case, Max.	0.21	°C/W	
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient, Max.	40	°C/W	

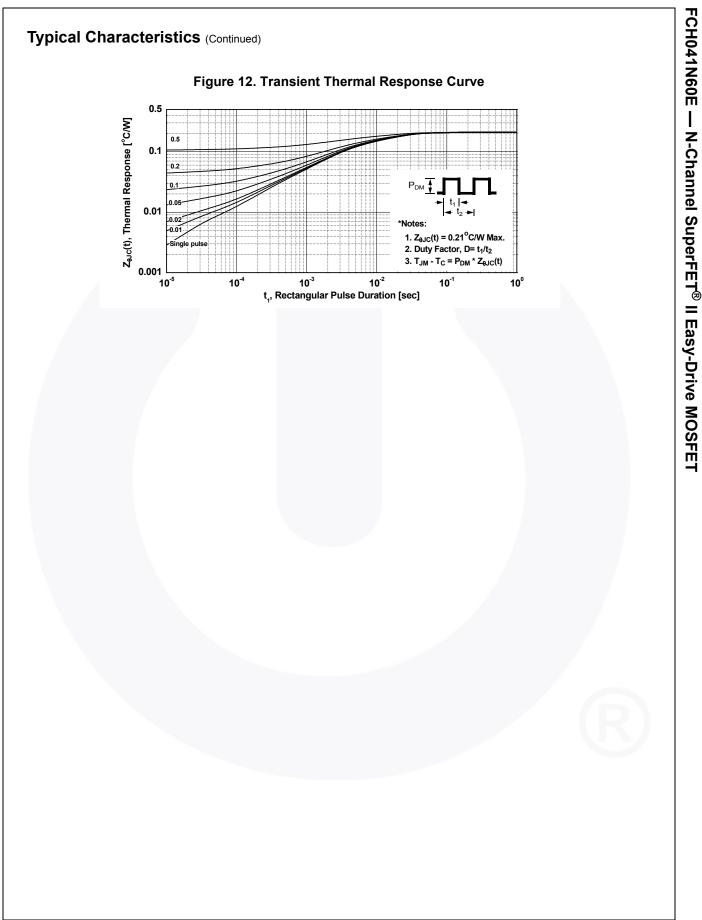
ECUDAA	mber	Part Number Top Mark Pa		ge Packing	Method	Reel Siz	е .	Tape Widt	h Q	uantity
FCH041	N60E	FCH041N60E	TO-24	7 Tu	be	N/A		N/A	3	0 units
Electrica	l Chara	acteristics T _C = 25°	C unless	otherwise note	d					
Symbol		Parameter			onditions		Min.	Тур.	Max.	Unit
- Off Charac	cteristics	6	1			1			I	
			I _D	$I_{D} = 10 \text{ mA}, V_{GS} = 0 \text{ V}, T_{C} = 25^{\circ}\text{C}$			600	-	-	v
BV _{DSS}	Drain to Source Breakdown Voltage		ID	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}, T_C = 150^{\circ}\text{C}$			650	-	-	v
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient			$I_D = 10$ mA, Referenced to $25^{\circ}C$			-	0.67	-	V/ºC
I _{DSS} Zero Gate Voltage Drain Current			V _{DS} = 600 V, V _{GS} = 0 V			-	-	1	μA	
	0.4.4.5			$_{\rm DS} = 480 \text{ V}, \text{ V}_{\rm GS}$		= 125°C	-	9.7	-	
GSS	Gate to Body Leakage Current		V	V _{GS} = ±20 V, V _{DS} = 0 V		- /	-	-	±100	nA
On Charac								1		1
V _{GS(th)}		reshold Voltage		$_{\rm GS}$ = V _{DS} , I _D = 2			2.5	-	3.5	V
R _{DS(on)}		ain to Source On Resistar		_{GS} = 10 V, I _D = 3			-	36	41	mΩ
9 _{FS}	Forward Transconductance		V	_{DS} = 20 V, I _D = 3	39 A		-	71	-	S
Oynamic C	Characte	ristics								
C _{iss}	Input Ca	pacitance	V	── V _{DS} = 100 V, V _{GS} = 0 V, ── f = 1 MHz		-	10300	13700	pF	
C _{oss}	Output C	apacitance				-	355	475	pF	
C _{rss}		Transfer Capacitance				-	4	6	pF	
C _{oss}	Output Capacitance			V _{DS} = 380 V, V _{GS} = 0 V, f = 1 MHz			-	187	-	pF
C _{oss} eff.	Effective Output Capacitance			V_{DS} = 0 V to 480 V, V_{GS} = 0 V			-	735	-	pF
ס _{g(tot)}		e Charge at 10V		V _{DS} = 380 V, I _D = 39 A, V _{GS} = 10 V		_	-	285	380	nC
ସୁ _{gs}		Source Gate Charge	VC			-	45	-	nC	
ସୁ _{gd}	Gate to Drain "Miller" Charge			(Note 4)			-	105	-	nC
ESR	Equivale	nt Series Resistance	f =	= 1 MHz			-	1.2	-	Ω
Switching	Charact	eristics								
d(on)		Delay Time					-	50	110	ns
r	Turn-On Rise Time			$V_{DD} = 380 \text{ V}, \text{ I}_{D} = 39 \text{ A},$			-	50	110	ns
d(off)	Turn-Off	Delay Time	vc	V _{GS} = 10 V, R _G = 4.7 Ω		_	-	320	650	ns
f	Turn-Off	Fall Time	(No	ote 4))		-	85	180	ns
Drain-Sou	rce Diod	e Characteristics								
s	Maximum	n Continuous Drain to Sou	irce Diod	Diode Forward Current			-	-	77	Α
SM	Maximum	n Pulsed Drain to Source I	Diode Fo	Forward Current			-	-	231	Α
/ _{SD}	Drain to Source Diode Forward Voltage		ltage \	V _{GS} = 0 V, I _{SD} = 39 A			-	-	1.2	V
	Reverse Recovery Time			V _{GS} = 0 V, I _{SD} = 39 A,			-	590		ns
rr	Reverse	Recovery Charge	c	dI _F /dt = 100 A/μ	6		-	18	-	μC

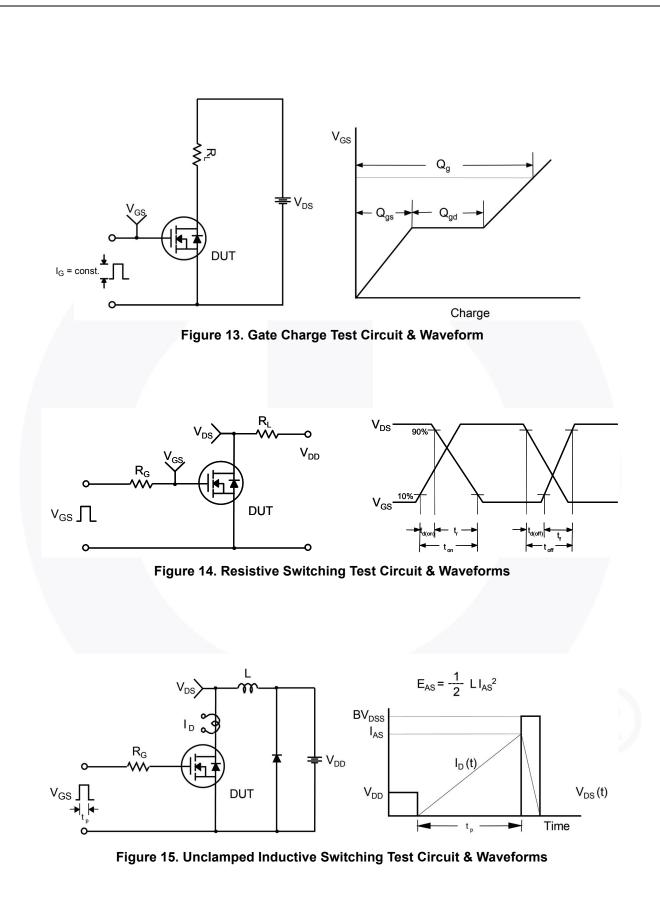
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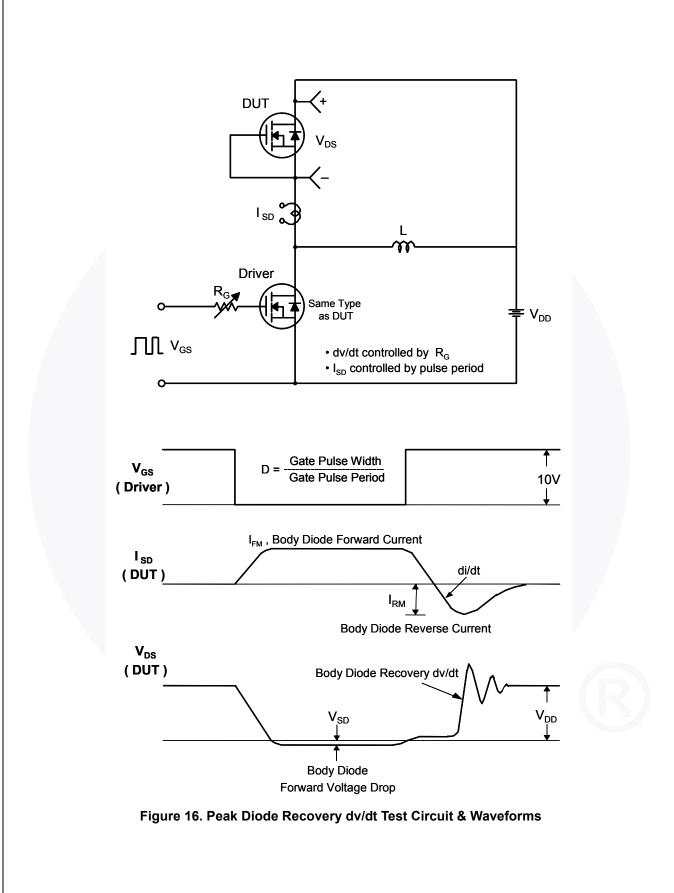




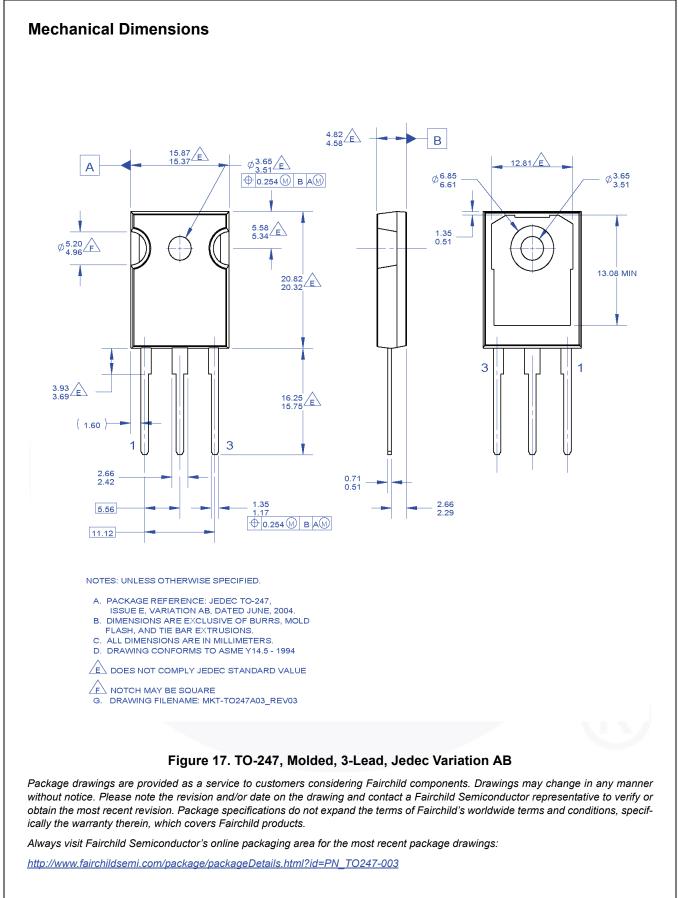




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